

Spectral Transmission Measurements of Thin Films



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Outline

- **Description of Transmission Measurement**
- **System Design Considerations**
- **Applications**
 - **Ultra-thin Metal Films**
 - **Multi-layer Optical Coatings and Films**
- **Summary**

Transmission Measurement System

- **CCD-based spectral measurement**
 - Visible light (380-780 nm) typical
 - Can extend into near IR (~1000-1100 nm) or into UV (down to 200 nm)
- **QTH or alternate broad spectrum lamp**
- **Software and hardware system enhancements for increased dynamic range of instrument**

Transmission Measurement Method

- **Measure known reference for calibration**
- **Measure sample**
- **Adjust signals**
 - subtraction of CCD dark current effects
 - parameters to increase dynamic range
- **Calculate percent transmission**
- **Apply result to current application**

In situ Transmission Measurement System Considerations

- **Sensor alignment**
 - **Repeatable normal incident alignment using fixtures common across multiple chamber configurations**
 - **Fixtures that retain alignment inside the vacuum, during pumpdown and opening of chamber (externally-mounted)**
 - **Fiber feed-throughs and vacuum compatible fiber optics for in-chamber fixtures**

In situ Transmission Measurement System Considerations

- **Hardware repeatability**
 - CCD/Spectrometer stability
 - Lamp Stability
 - Alignment repeatability/stability
- **Integration Issues**
 - Interaction with process control software
 - Ability to re-calibrate as necessary

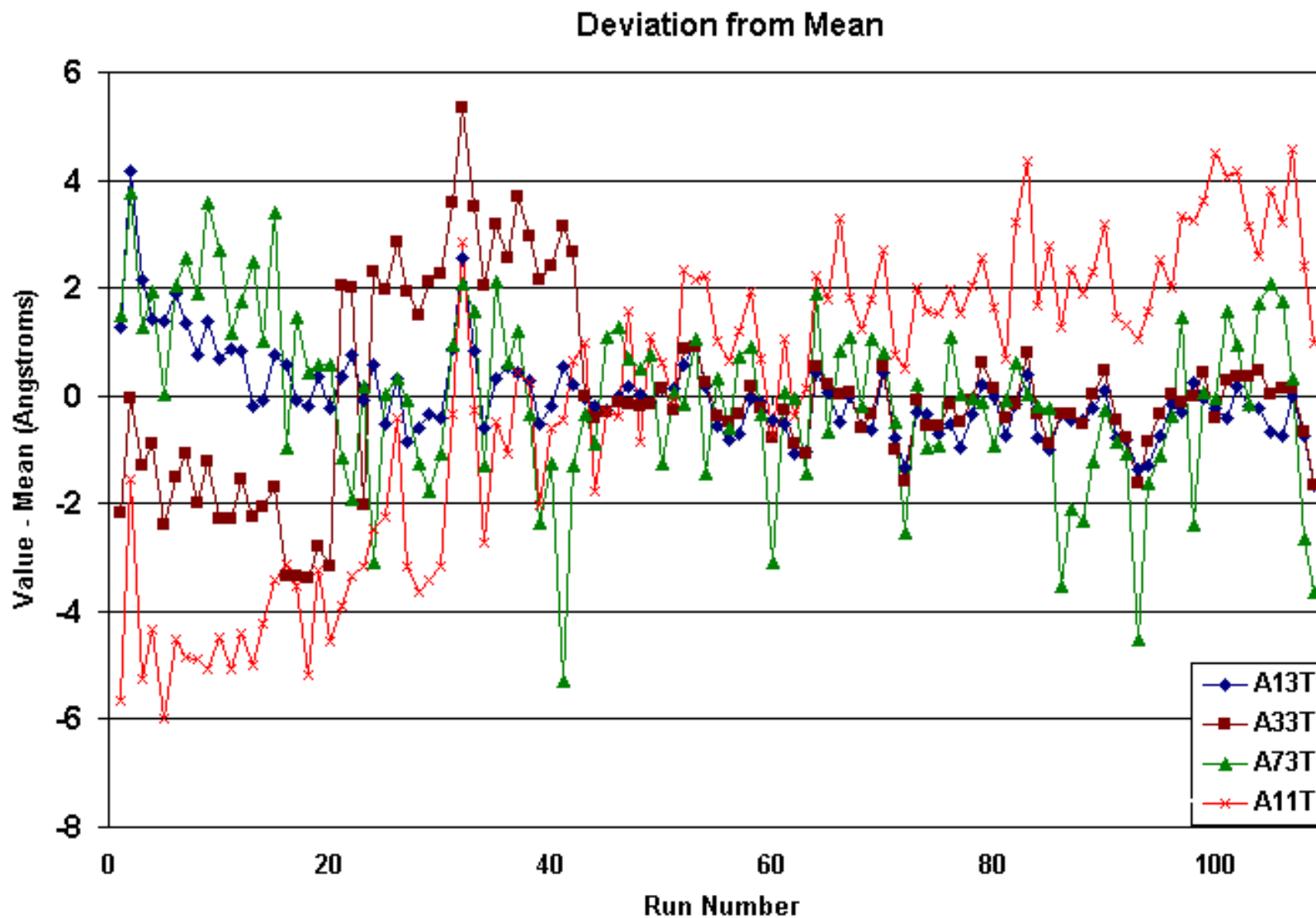
Metal Film Thickness Measurements

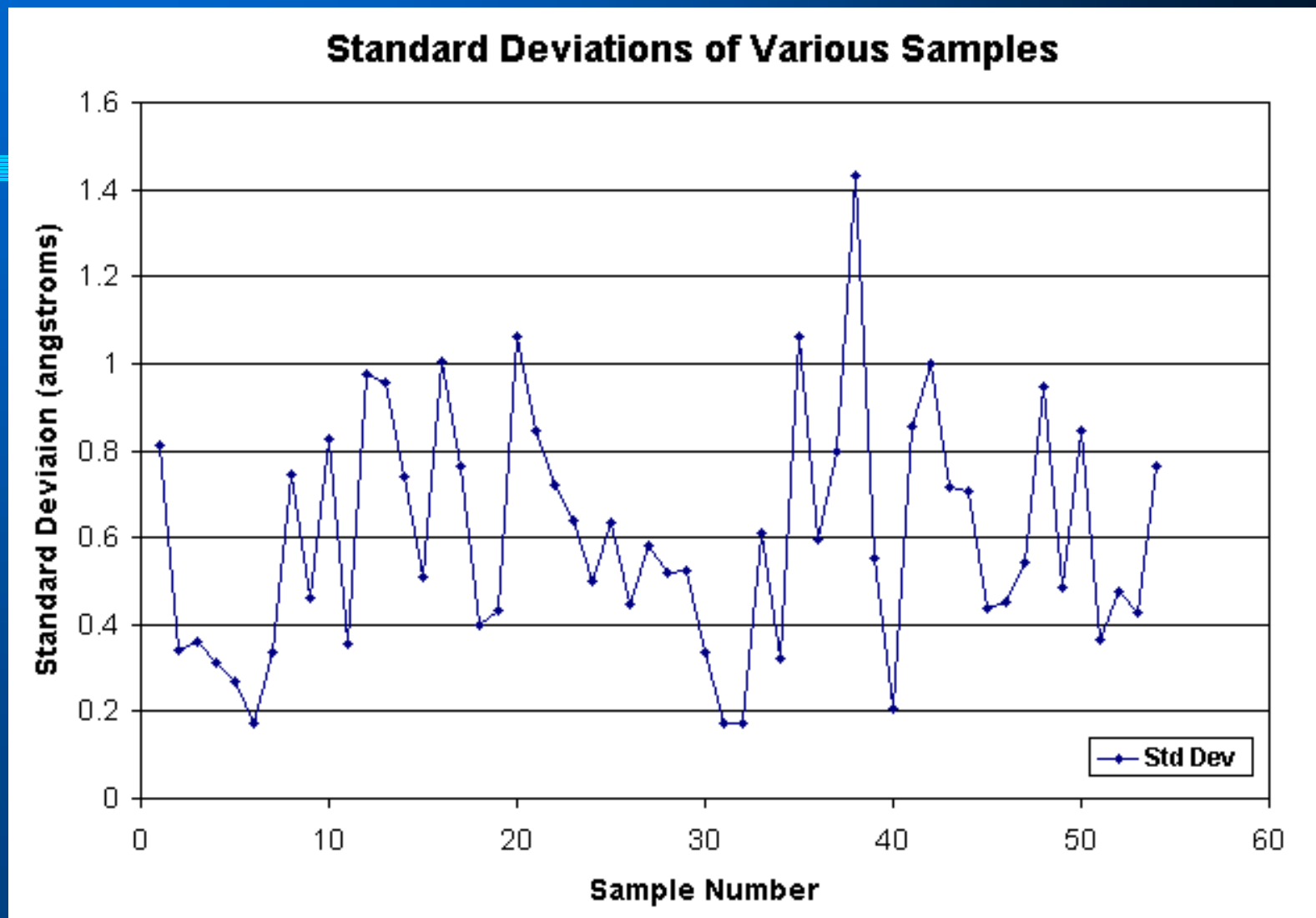
- **Goal: Measure ultra-thin metal films for process control (SPC & in situ feedback)**
- **Requirements:**
 - Measure variety of metals
 - Demonstrate repeatability of measurement (sample-to-sample and unit-to-unit)
 - Measure optically thin and thick metals on same instrument (large dynamic range)

Metal Film Thickness Measurements

- **Instrument Configuration Procedure:**
 - Measure Transmission / Optical Density (O.D. = $\log [100/\%T]$) of set of Metal samples of varying thickness
 - Measure sample thicknesses using alternate technique (XRR and XRF used here)
 - Create correlation equation(s) between O.D. data and thickness from alternate method

Results





Summary of Metal Thickness Monitor

- **Typical measurement repeatability $3\sigma < 6\text{\AA}$**
 - Elemental metal lattice constants $\sim 3 - 4 \text{\AA}$
 - Actual thickness variation not accounted for (absolutely uniform sample thickness assumed)
- **Over 3.5 orders of magnitude dynamic range**
 - Measure metals from nominally 0 O.D. (100%T) to over 5 O.D. (0.001%) with manual instrument adjustment (may be automated)

Limitations of Metal Thickness Monitor

- **Single layer metal only**
 - Method could be extended to extract thicknesses of multi-layer stack with additional modeling
- **Accuracy dependent on quality of:**
 - Independent thickness measurement (XRR/XRF/...)
 - Correlation Model
 - Process control (quality/repeatability)

Multi-Layer Thin Film Monitor

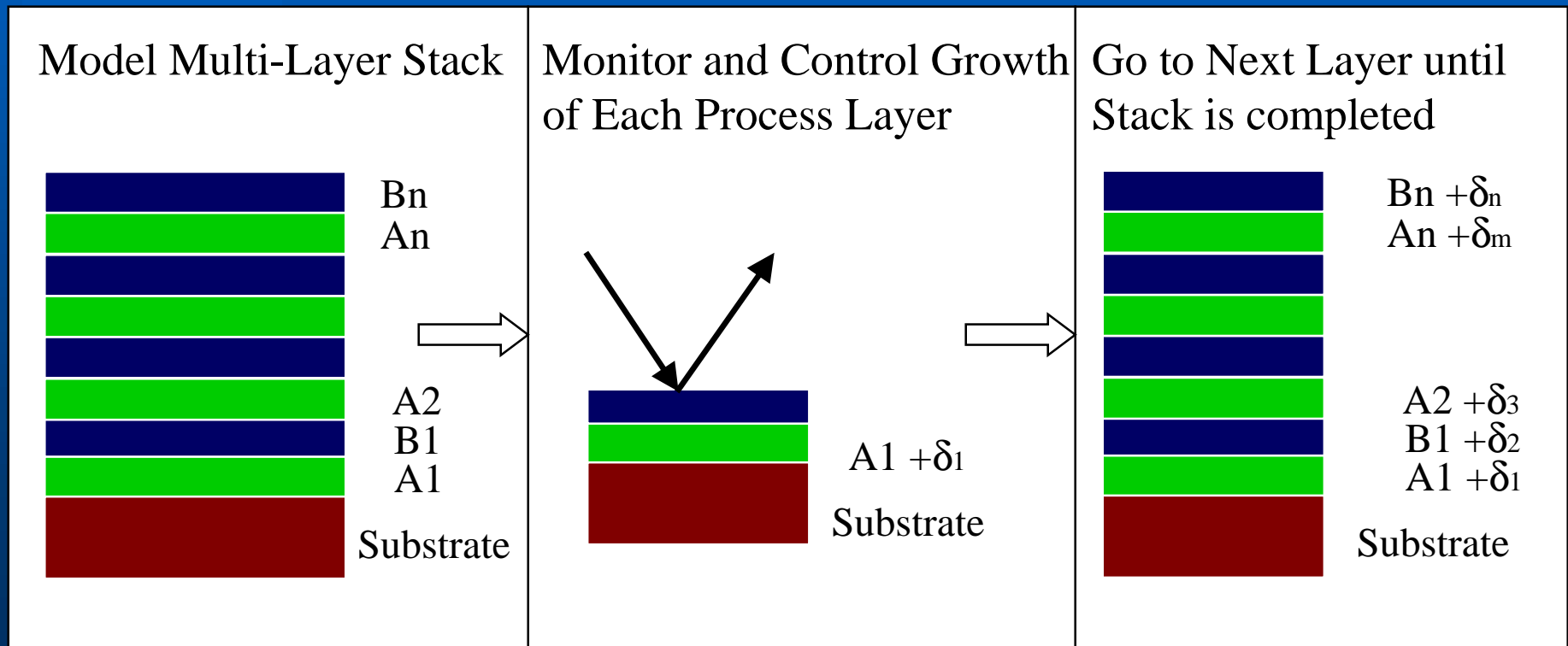
- **Goal: Monitor and control multi-layer thin films during deposition.**
- **Requirements:**
 - Target application: optical coatings (SiO_2 , TiO_2)
 - Separately control each of 30-40+ layers
 - Control overall final optical properties of stack

Multi-Layer Optical Coating Monitor - System Considerations

- **Systemic deviation from model**
- **Difficulties in monitoring new layers as more layers are added to the stack**

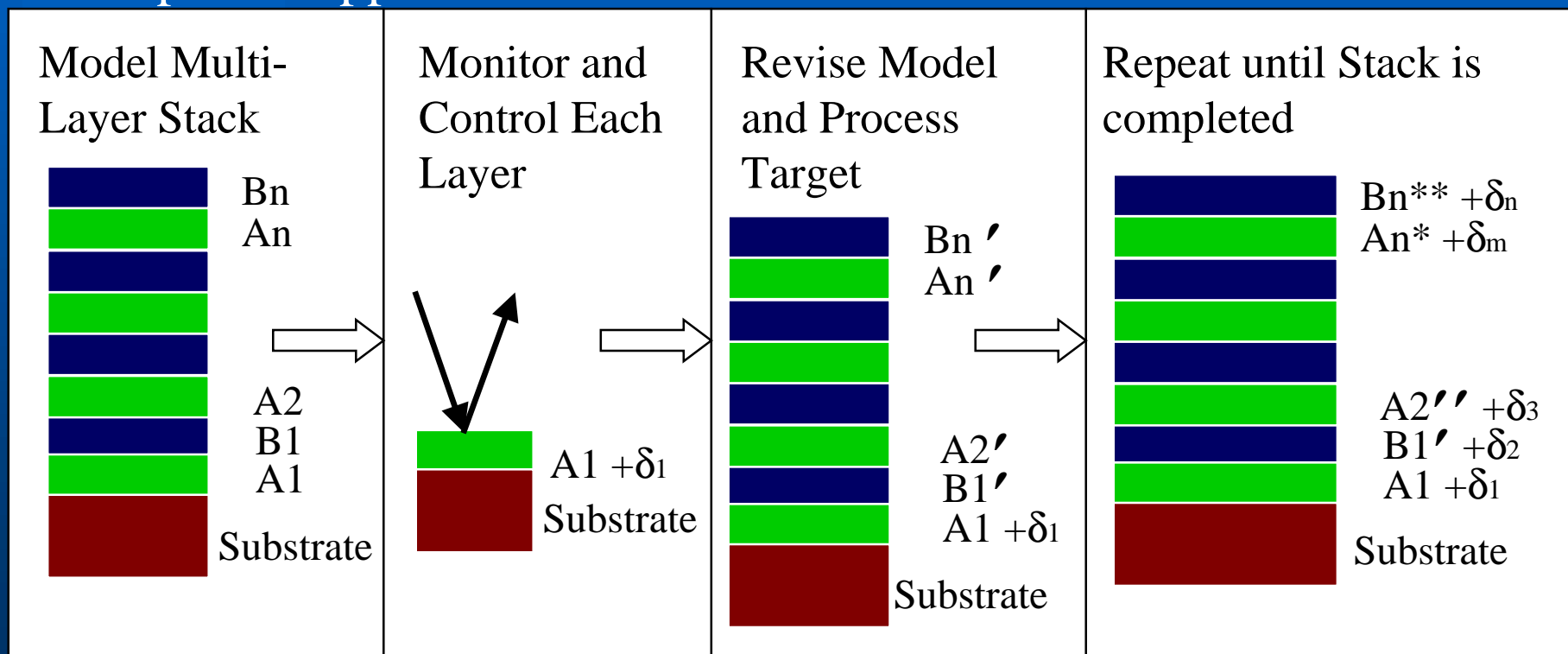
Systemic Variation From Model

Traditional Process Model:



Systemic Variation from Model:

Proposed Approach:



Concept: Vidal and Pelletier, *Applied Optics* 18 (22), 15 Nov 1979, 3857

Techniques for Distinguishing Between Layers

- **Do complete modeling of sub-layers and current layer**
- **Use changes in signal (Virtual Interface)**
- **Compare signal to model or prior measurements (e.g. Neural Net)**
- **Measure separate substrate/sample**
 - **Optical coaters often have built in chip-changers for this purpose**

Optical Coating Monitor

- **Reflection on bare glass substrate for each layer (use chip-changer to introduce new substrate)**
 - Use signals from this for endpoint of each layer
- **Transmission through product for revising model at end of each layer**
 - Modify remaining layer thicknesses

Optical Coating Monitor - Limitations

- **Need to be able to revise model based on previous layer(s)**
 - **Optical, electrical, thermal, mechanical (stresses) effects must be taken into account**
 - **Must be fast enough to be useful in real time**
 - **Process tool may be able to suspend process through target shutters or gas flow valves**
 - **Previous layer measurements must be accurate to avoid introduction of error**

Optical Coating Monitor - Limitations

- **Need method of monitoring growth of current layer with complex underlayers**
 - Modeling becomes difficult or impossible to independently determine parameters of current layer
 - Optical coating chambers typically design around this through use of chip-changers

Summary and Conclusions

- **Spectral transmission measurements can be used in situ to monitor and control processes**
- **Ultra-thin metal films can be measured with repeatability of 1-2 monolayers**
- **Multi-layer thin film growth can be monitored, and growth targets revised during process**